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UNIVERSITI TUN HUSSEIN ONN MALAYSIA

**FINAL EXAMINATION
SEMESTER II
SESSION 2015/2016**

COURSE NAME : PHOTONIC DEVICES
COURSE CODE : BED 40902
PROGRAMME : BEJ
EXAMINATION DATE : JUNE/JULY 2016
DURATION : 2 HOURS 30 MINUTES
INSTRUCTION : ANSWER ALL QUESTIONS

THIS QUESTION PAPER CONSISTS OF FIVE (5) PAGES

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- Q1** (a) In microelectronic semiconductor fabrication, band gap is very important to determine the applications.
- (i) Explain the importance of direct and indirect band gap. (4 marks)
 - (ii) Illustrate direct and indirect band gap to show the differences and provide one electronic application using those band gaps. (6 marks)
 - (iii) Give an example how indirect band gap can be tuned into direct band gap. (2 marks)
- (b) A semiconductor material has an optical band gap of 2.2 eV.
- (i) Determine the light wavelength that would be absorbed by the material. (4 marks)
 - (ii) Analyze **TWO (2)** properties of the n-type semiconductor material that suit the requirement of a solar cell device. (2 marks)
 - (iii) Doping process is a technique to tune the semiconductor material band gap. Explain the reason for the decrement of band gap as a result of introducing metal ions into the material. (2 marks)
- (c) Electron excitation is divided into two types.
- (i) With the aid of figures, differentiate the radiative and non-radiative transition of a semiconductor material. (4 marks)
 - (ii) Identify the technique of measurement to determine the radiative and non-radiative transition of materials. (1 mark)
- Q2** (a) Solar cell is one of the fastest growing renewable energy sources.
- (i) Propose a mechanism of energy conversion from light to electricity in solar cell. (5 marks)

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- (ii) Draw the conceptual diagram of electron separation for solar cell devices. (2 marks)
- (iii) Analyze the process of electron-hole recombination which degrade the solar cell performance. (4 marks)
- (b) The CEO of Matrix Sdn Bhd offers a position of Material Engineer with a task to produce blue LED using ZnO with band gap of 3.3 eV. Suggest how to produce the new product by band alignment strategy. (8 marks)
- (c) Draw a single junction LED and explain its application in electronic devices. (6 marks)
- Q3** (a) Design a basic laser diode configuration and how does the design can emit laser. (8 marks)
- (b) Explain the quantum efficiency and analyze its application in optoelectronic design. (8 marks)
- (c) The emerging of nanotechnology has enhanced the performance of laser diode. Draw the schematic diagram of a laser diode employing nanostructures and analyze the reason the performance could be enhanced. (9 marks)
- Q4** (a) Based on **Figure Q4(a)**, deduce the equation for field factor and energy conversion efficiency. Hence, calculate the efficiency and field factor of the information in the figure. (10 marks)
- (b) A solar cell company is hiring a process engineer to manufacture a solar cell using Indium tin oxide (ITO), Cuprous oxide (Cu_2O), Zinc oxide (ZnO) and Aluminium (Al) with parameters as shown in **Table 1**.
- (i) Draw the energy band alignment. (10 marks)

- (ii) Construct a single junction solar cell using the materials given.

Table 1: Semiconductor material parameters

Material	Band gap energy (E_g)	Valence energy (E_v)	Conduction energy (E_c)
TiO ₂	3.0 eV	-6.7 eV	-3.7 eV
ITO	-	-	-4.8 eV
Cu ₂ O	2.2 eV	-5.4	-3.2 eV
Al	-	-	-4.1 eV

(5 marks)

- END OF QUESTION -



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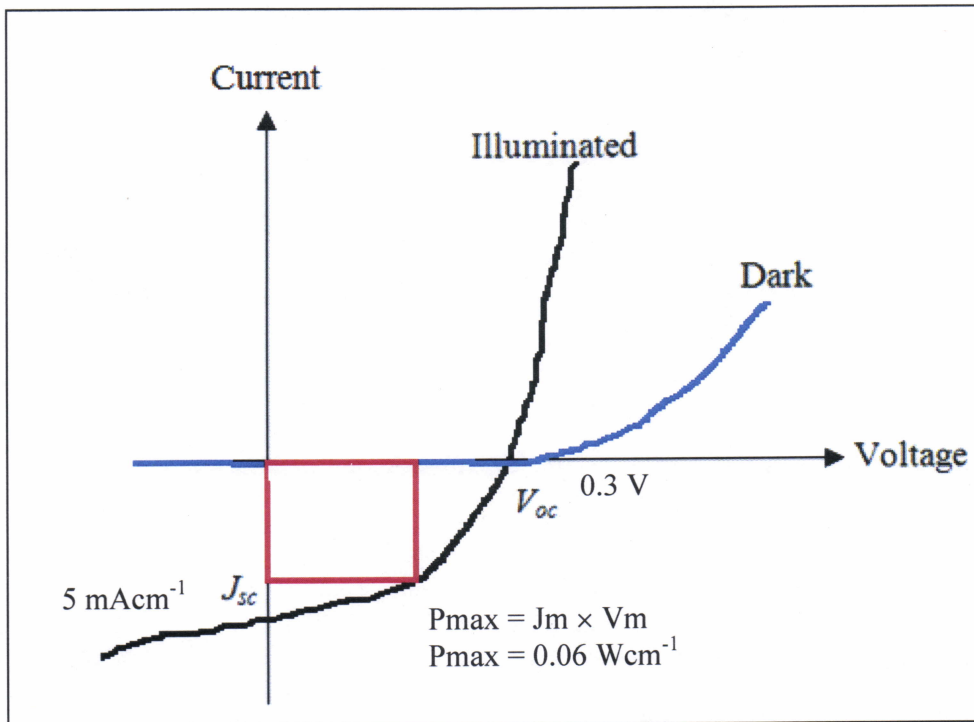


Figure Q4(a)

